

## Low Voltage CMOS Driver Circuit

### Description

The e5130 contains 4 independent driver outputs with an ON resistance of typ.  $25\ \Omega$  ( $15\ \Omega$ ) for the P-channel output transistors and typ.  $20\ \Omega$  ( $13\ \Omega$ ) for the N-channel output transistors; at a supply voltage of 1.5 V (3 V). To obtain a fast transition of the outputs, even for slow rise/-fall time input signals, all digital inputs (IN1 ... IN4) have a schmitt-trigger characteristic; with a hysteresis of typ.

50 mV. If a higher driving capability is needed, all inputs and outputs may be connected in parallel. In this case the rise/-fall time of the input signals IN1 ... IN4 must be less than 200 nsec. Due to the fast switching characteristic of the tristatable output drivers, the circuit is also suited as low voltage bus driver.

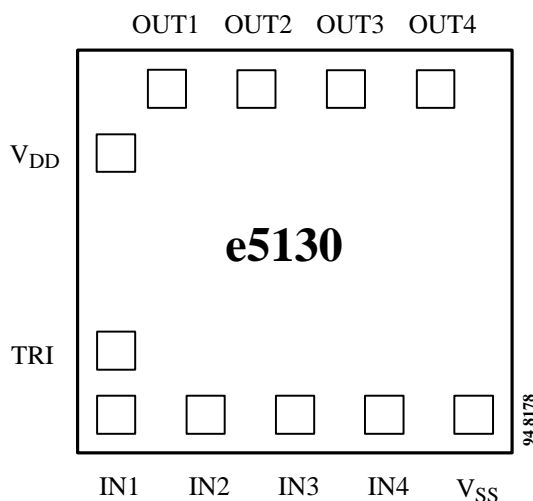
### Features

- 1.1 – 3.6 V operating voltage range
- 4 non-inverting, tristatable drivers for the following applications:
  - Motor driver for bipolar stepper motors in watch/-clock applications
  - Driver for piezoelectric transducers (buzzer)
  - LED Driver
  - Line driver for medium speed applications

### Advantages

- High load current at low supply voltage
- Replaces several discrete transistors
- Tri-state operation possible
- Possible applications:
  - Motor driver
  - Radio controlled clock/watch
  - Line driver for mini-computer, laptop
  - LED driver
  - Relay driver

### Pad configuration

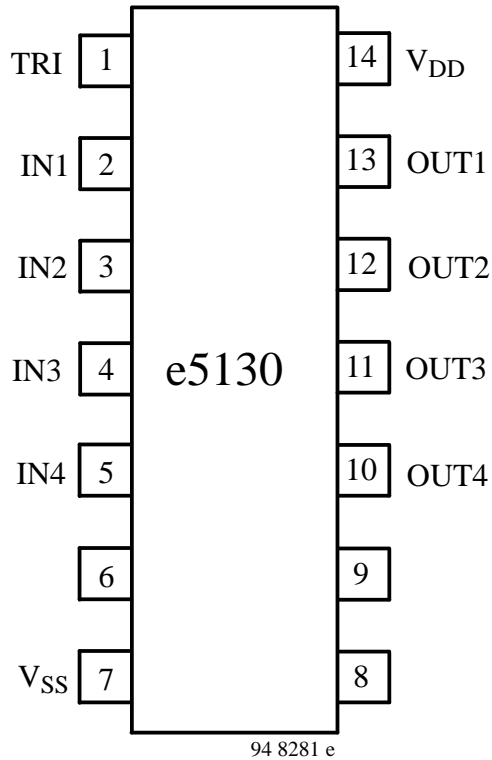


Name	Description
V <sub>DD</sub>	Positive supply voltage
V <sub>SS</sub>	Negative supply voltage
IN1 ... IN4	Digital inputs
TRI	Tristate input
OUT1 ... OUT4	Drive outputs

Chipsize: x = 1.08 mm, y = 1.42 mm, padwindow 90 x 90  $\mu$

## e5130

### Pinning



### Pin Description

Pin	Symbol	Function
1	TRI	Tristate input
2	IN1	Input 1
3	IN2	Input 2
4	IN3	Input 3
5	IN4	Input 4
6	–	
7	V <sub>SS</sub>	Negative supply voltage
8	–	
9	–	
10	OUT4	Output 4
11	OUT3	Output 3
12	OUT2	Output 2
13	OUT1	Output 1
14	V <sub>DD</sub>	Positive supply voltage

### Absolute Maximum Ratings

Parameters	Symbol	Value	Unit
Supply voltage	V <sub>DD</sub> – V <sub>SS</sub>	– 0.3 to + 5	V
Input voltage range, all inputs	V <sub>I</sub>	V <sub>SS</sub> – 0.3 to V <sub>DD</sub> + 0.3	V
Power dissipation (DIL package)		125	mW
Operating ambient temperature range		– 20 to + 70	°C
Storage temperature range		– 40 to + 125	°C
Lead temperature during soldering at 2 mm distance, 10 s		260	°C

Absolute maximum ratings define parameter limits which, if exceeded, may permanently change or damage the device.

All inputs and outputs on EURO SIL electronic GmbH circuits are highly protected against electrostatic

discharges.

However, precautions to minimize build-up of electrostatic charges during handling are recommended.

The circuits are protected against supply voltage reversal for typically 5 minutes, if the current is limited to 120 mA.

## Operating Characteristics

$V_{SS} = 0\text{ V}$ ,  $V_{DD} = +1.5\text{ V}$ ,  $T_{amb} = +25\text{ °C}$ , unless otherwise specified.

All voltage levels are measured with reference to  $V_{SS}$ .

Parameters	Test Conditions / Pin	Symbol	Min	Typ	Max	Unit
Operating voltage		$V_{DD}$	1.1		3.6	V
Operating temperature		$T_{amb}$	-10		60	°C
Operating current (standby)	$V_{DD} = 3.6\text{ V}$ , $R_{L12} = R_{L34} = \infty$ , IN1 to IN4 at $V_{DD}$ or $V_{SS}$ , TRI at $V_{SS}$	$I_{DD}$		0.05	1	μA
<b>Drive output OUT1 to OUT4</b>						
Output current	$V_{DD} = 1.2\text{ V}$ , $R_{L12} = R_{L34} = 200\ \Omega$	$I_{OUT}$	± 4.3	± 4.75		mA
Output current	$V_{DD} = 1.5\text{ V}$ , $R_{L12} = R_{L34} = 200\ \Omega$	$I_{OUT}$	± 5.7	± 6.20		mA
Output current	$V_{DD} = 3.0\text{ V}$ , $R_{L12} = R_{L34} = 200\ \Omega$	$I_{OUT}$	± 12	± 13		mA
Delay time	$V_{DD} = 3\text{ V}$ , $C_L = 50\text{ pF}$	$T_{Dr}$ , $T_{Df}$		35	60	ns
Delay time	$V_{DD} = 1.5\text{ V}$ , $C_L = 50\text{ pF}$ , see figure 2, note 1	$T_{Dr}$ , $T_{Df}$		80	150	ns
Rise/-fall time	$V_{DD} = 3\text{ V}$ , $C_L = 50\text{ pF}$	$t_r$ , $t_f$		8	15	ns
Rise/-fall time	$V_{DD} = 1.5\text{ V}$ , $C_L = 50\text{ pF}$ , see figure 2, note 2	$t_r$ , $t_f$		12	25	ns
<b>Digital input IN1 to IN4</b>						
Input current	$V_{IL} = 0\text{ V}$	$I_{IL}$			-100	nA
Input current	$V_{IH} = V_{DD}$	$I_{IH}$			100	nA
Threshold	V	$V_{TH}$		$V_{DD}/2$		V
Hysteresis	mV	$V_{HYST}$		50		mV
<b>Tristate input TRI</b>						
Input current TRI	$V_{IH} = V_{DD}$	$I_{IH}$	0.15	0.4	1.2	μA

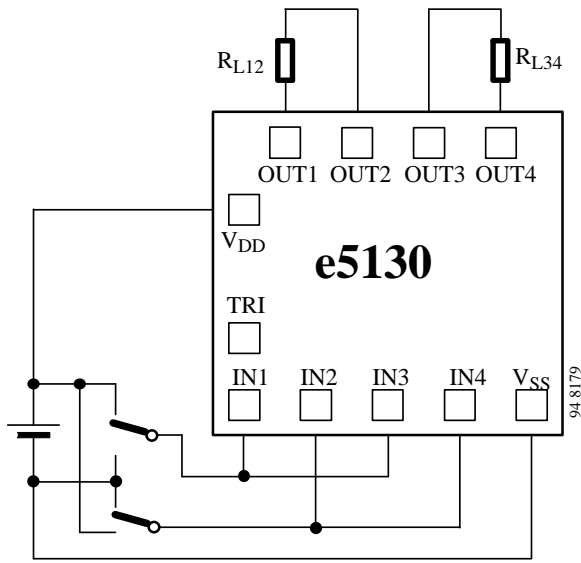


Figure 1 Test circuit.

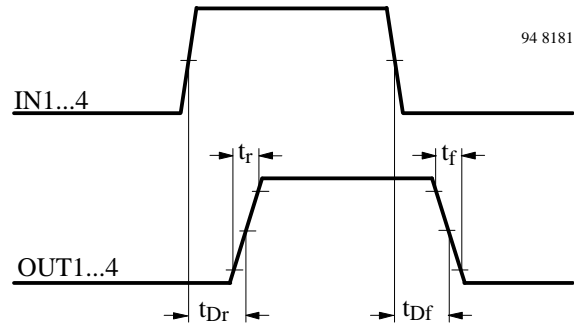


Figure 2

Note 1:  $t_{Dr}$ ,  $t_{Df}$  is defined at 50% of supply voltage  
 Note 2:  $t_r$ ,  $t_f$  is defined from 10% to 90%, resp. 90% to 10% of supply voltage

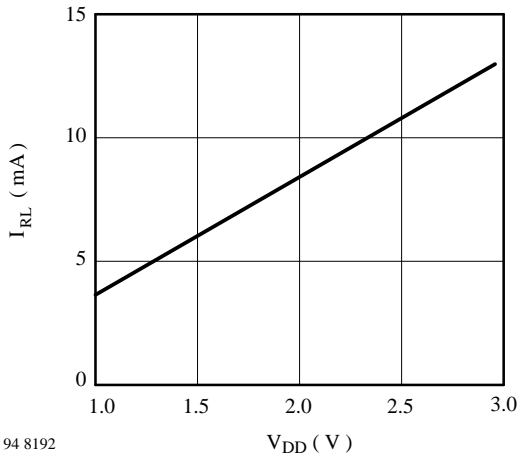


Figure 3 Typical current into 200  $\Omega$  load resistor, condition as per figure 1

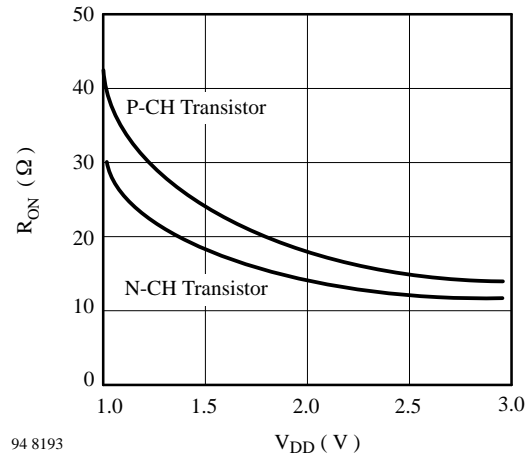


Figure 4 Typical output on-resistance vs. supply voltage at  $V_{DS} = 0.2$  V

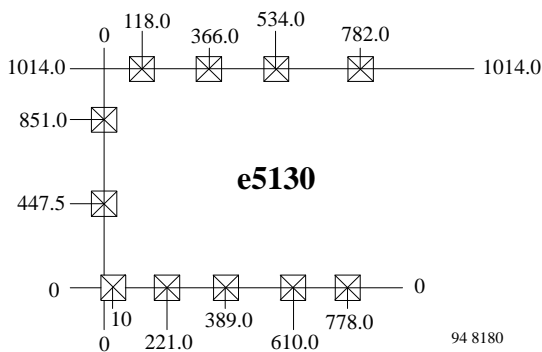
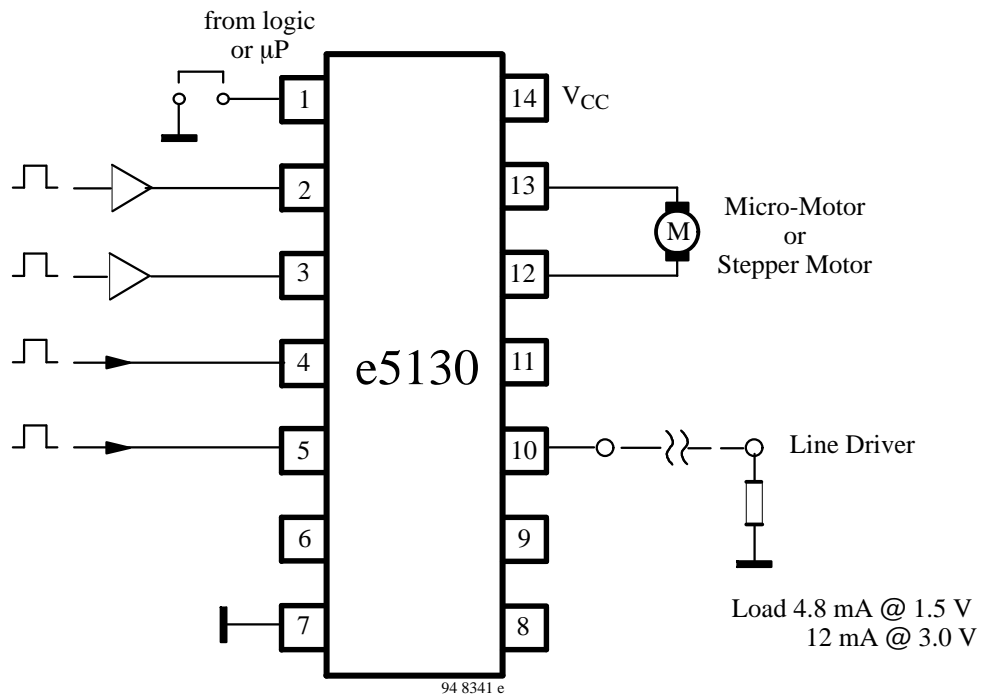


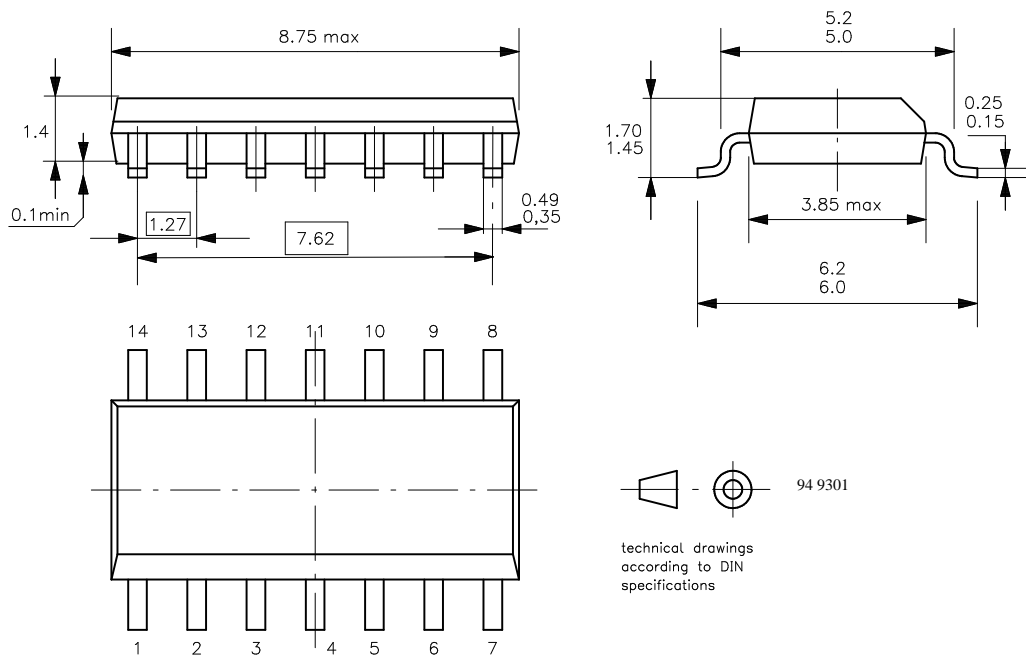
Figure 5 Pad coordinates

## Application Circuit



## Dimensions in mm

Package: SO 14



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It is the policy of **TEMIC TELEFUNKEN microelectronic GmbH** to

1. Meet all present and future national and international statutory requirements and
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

Of particular concern is the control or elimination of releases into the atmosphere of those substances which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) will soon severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

**TEMIC TELEFUNKEN microelectronic GmbH** semiconductor division has been able to use its policy of continuous improvements to eliminate the use of any ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA and
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

**TEMIC** can certify that our semiconductors are not manufactured with and do not contain ozone depleting substances.

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